



Combined local microchannel-scale CFD modeling and global chip scale network modeling for electronics cooling design

R. Wälchli^{a,b,*}, T. Brunschwiler^a, B. Michel^a, D. Poulikakos^b

^aIBM Research GmbH, Zurich Research Laboratory, 8803 Rüschlikon, Switzerland

^bLaboratory of Thermodynamics in Emerging Technologies, Department of Mechanical and Process Engineering ETH Zürich, 8092 Zürich, Switzerland

ARTICLE INFO

Article history:

Received 17 December 2008

Accepted 9 October 2009

Available online 11 December 2009

Keywords:

Microchannel

Liquid cooling

Heat transfer in electronics

ABSTRACT

Microchannel cold plates enjoy increasing interest in liquid cooling of high-performance computing systems. Fast and reliable design tools are required to comply with the fluid mechanics and thermal specifications of such complex devices. In this paper, a methodology accounting for the local as well as the device length scales of the involved physics is introduced and applied to determine the performance of a microchannel cooler. A unit cell of the heat transfer microchannel system is modeled and implemented in conjugate CFD simulations. The fluidic and thermal characteristics of three different cold plate mesh designs are evaluated. Periodic boundary conditions and an iteration procedure are used to reach developed flow and thermal conditions. Subsequently, two network-like models are introduced to predict the overall pressure drop and thermal resistance of the device based on the results of the unit cell evaluations. Finally, the performance figures from the model predictions are compared to experimental data. We illustrate the cooling potential for different channel mesh porosities and compare it to the required pumping power. The agreement between simulations and experiments is within 2%. It was found that for a typical flow rate of 250 ml/min, the thermal resistance of the finest microchannel network examined is reduced by 7% and the heat transfer coefficient is increased by 25% compared to the coarsest channel network. On the other hand, an increase in pressure drop by 100% in the case of densest channel network was found.

© 2009 Elsevier Ltd. All rights reserved.

1. Introduction

In bipolar microprocessor technology, liquid cooling of electronics applications has been ubiquitous and highly needed in order to achieve high power dissipation. This situation changed rapidly when the industry switched from bipolar to *complementary metal oxide semiconductor* (CMOS) chip technology. Due to low heat fluxes of the first chip generations, CMOS microprocessors immediately dropped the need for liquid cooling. However, aligning with Moore's law a continuous increase in power dissipation of high-performance computing systems has been taking place. Furthermore, the idea of collecting excess heat from data centers for reuse are expected to leverage low resistance liquid coolers for future thermal packaging solutions [1].

Microchannel cold plates have been demonstrated for the first time by Tuckerman and Pease with a cooling performance up to 790 W/cm² [2]. However, manufacturing difficulties, high pressure

drop, and cost issues hindered this innovative concept for being implemented in electronics applications. Since the introduction of the flip chip and C4 technology that removed the requirement for wire bonding the entire backside of the die became available for heat removal. Thermal interface materials allow for a low heat flow resistance between the chips and the heat absorber device. Recent backside liquid cooling approaches ([3,4]) have demonstrated high cooling potential. In Brunschwiler et al. [3] direct water jet impingement with 50,000 nozzles arranged in a hierarchical manner was used to cool the backside of the chip. At a flow rate of 2.5 liter per minute (lpm) and a pressure drop of 0.35 bar a thermal resistance value of 15.0 K mm² W⁻¹ was reached. However, direct contact of fluid with the microprocessor is delicate and requires advanced sealing and assembling. In the work of Colgan et al. [4], micromachining in silicon was used to build three-dimensional heat transfer structures of the size of 20 × 20 mm². At a flow rate of 1.5 lpm and a pressure drop of 0.4 bar a unit thermal resistance of 15.9 K mm² W⁻¹ was achieved. A comprehensive study of high heat flux cooling technologies can be found in [5].

High convective heat transfer and low pressure drop is desired in order to meet performance requirements mentioned above. Precise prototyping and mass manufacturing technologies are needed

* Corresponding author. Address: IBM Research GmbH, Zurich Research Laboratory, Saumerstreet 4, 8803 Rüschlikon, Switzerland. Tel.: +41 44 724 8272; fax: +41 44 724 8958.

E-mail address: eto@zurich.ibm.com (R. Wälchli).

Download English Version:

<https://daneshyari.com/en/article/658856>

Download Persian Version:

<https://daneshyari.com/article/658856>

[Daneshyari.com](https://daneshyari.com)